

0.8V Reference Ultra Low Dropout (0.2V@5A) Linear Regulator

Features

- · Ultra Low Dropout
 - 0.2V (typical) at 5A Output Current
- Low ESR Output Capacitor (Multi-layer Chip Capacitors (MLCC)) Applicable
- 0.8V Reference Voltage
- · High Output Accuracy
 - ±1.5% over Line, Load and Temperature
- Fast Transient Response
- Adjustable Output Voltage by External Resistors
- Power-On-Reset Monitoring on Both VCNTL and VIN Pins
- Internal Soft-Start
- · Current-Limit Protection
- Under-Voltage Protection
- Thermal Shutdown with Hysteresis
- · Power-OK Output with a Delay Time
- · Shutdown for Standby or Suspend Mode
- · Simple SOP-8-P Package with Exposed Pad
- Lead Free Available (RoHS Compliant)

Applications

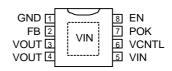
- Front Side Bus VTT (1.2V/5A)
- Note Book PC Applications
- · Motherboard Applications

General Description

The APL5912 is a 5A ultra low dropout linear regulator. This product is specifically designed to provide well supply voltage for front-side-bus termination on motherboard and NB applications. The IC needs two supply voltages, a control voltage for the circuitry and a main supply volatege for power conversion, to reduce power dissipation and provide extremely low dropout. The APL5912 integrates many functions. A Power-On-Reset (POR) circuit monitors both supply voltages to prevent wrong operations. A thermal shutdown and current limit functions protect the device against thermal and current over-loads. A POK indicates the output status with time delay which is set internally. It can control other converter for power sequence. The APL5912 can be enabled by other power system. Pulling and holding the EN pin below 0.3V shuts off the output.

The APL5912 is available in SOP-8-P package which features small size as SOP-8 and an Exposed Pad to reduce the junction-to-case resistance, being applicable in 2~3W applications.

Pin Configuration

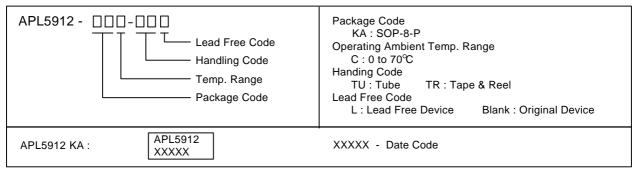


SOP-8-P (Top View)

= Exposed Pad (connected to V_{IN} plane for better heat dissipation)

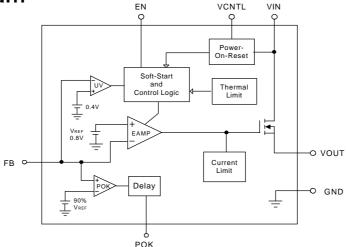


Ordering and Marking Information



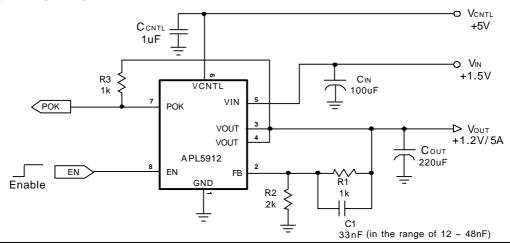
Note: ANPEC lead-free products contain molding compounds/die attach materials and 100% matte tin plate termination finish; which are fully compliant with RoHS and compatible with both SnPb and lead-free soldiering operations. ANPEC lead-free products meet or exceed the lead-free requirements of IPC/JEDEC J STD-020C for MSL classification at lead-free peak reflow temperature.

Block Diagram



Typical Application Circuit

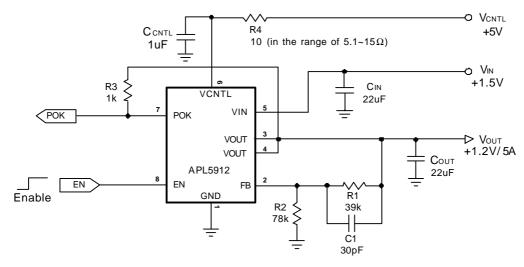
1. Using an Output Capacitor with ESR≥18mΩ





Typical Application Circuit (Cont.)

2. Using an MLCC as the Output Capacitor



V _{OUT} (V)	R1 (kΩ)	R2 (kΩ)	C1 (pF)
1.05	43	137.6	27
1.5	27	30.86	36
1.8	15	12	68

Absolute Maximum Ratings

Symbol	Parameter	Rating	Unit
VCNTL	VCNTL Supply Voltage (VCNTL to GND)	-0.3 ~ 7	V
Vin	VIN Supply Voltage (VIN to GND)	-0.3 ~ 3.3	V
V _{I/O}	EN and FB to GND	-0.3 ~ VCNTL+0.3	V
VPOK	POK to GND	-0.3 ~ 7	V
PD	Average Power Dissipation	3	W
PPEAK	Peak Power Dissipation (<20mS)	20	W
TJ	Junction Temperature	150	°C
Тѕтс	Storage Temperature	-65 ~ 150	°C
Tsdr	Soldering Temperature, 10 Seconds	300	°C
Vesd	Minimum ESD Rating (Human Body Mode)	±2	kV



Thermal Characteristics

Symbol	Parameter	Value	Unit
θја	Junction-to-Ambient Thermal Resistance in Free Air (Note)	40	°C/W

Note:

 θ_{JA} is measured with the component mounted on a high effective thermal conductivity test board in free air. The exposed pad of SOP-8-P is soldered directly on the PCB.

Recommended Operating Conditions

Symbol	Parameter	Range	Unit
VCNTL	VCNTL Supply Voltage	3.1 ~ 6	V
Vin	VIN Supply Voltage	1.1 ~ 3.3	V
Vouт	Output Voltage Vcntl=3.3±5% Vcntl=5.0±5%	0.8 ~ 1.2 0.8 ~ Vin-0.2	V
Іоит	VOUT Output Current	0 ~ 6	А
TJ	Junction Temperature	-25 ~ 125	°C

Electrical Characteristics

Refer to the typical application circuit. These specifications apply over, $V_{CNTL} = 5V$, $V_{IN} = 1.5V$, $V_{OUT} = 1.2V$ and $T_A = 0$ to 70° C, unless otherwise specified. Typical values refer to $T_A = 25^{\circ}$ C.

Symbol Parameter	Baramatar	Test Conditions	APL5912			Unit
	Parameter	rest Conditions	Min	Тур	Max	Unit
SUPPLY	CURRENT					
ICNTL	VCNTL Nominal Supply Current	EN = VCNTL	0.4	1	8	mA
Isp	VCNTL Shuntdown Current	EN = GND		180	300	μΑ
POWER	-ON-RESET					
	VCNTL POR Threshold	VCNTL Rising	2.7	2.9	3.1	V
	VCNTL POR Hysteresis			0.4		V
	VIN POR Threshold	VIN Rising	8.0	0.9	1.0	V
	VIN POR Hysteresis			0.5		V



Electrical Characteristics (Cont.)

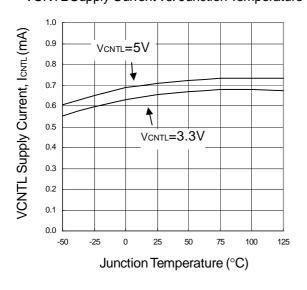
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Cumb al	Doromatar	Took Oom distings	APL5912			Unit
Symbol	Parameter	Test Conditions	Min	Тур	Max	Offic
OUTPUT	VOLTAGE					
VREF	Reference Voltage	FB =VOUT		0.8		V
	Output Voltage Accuracy	Iо∪т=0A ~ 5A, Т」= -25 ~125°С	-1.5		+1.5	%
	Line Regulation	VCNTL=3.3 ~ 5V		0.06	0.15	%
	Load Regulation	IOUT=0A ~ 5A		0.06	0.15	%
DROPOL	JT VOLTAGE		I.		ı	
	Duran en d'Aldre en e	IOUT = 5A, VCNTL=5V, TJ= 25° C		0.15	0.2	V
	Dropout Voltage	IOUT = 5A, VCNTL=5V, TJ= -25~125°C			0.25	V
PROTEC	TION			•		
		VCNTL=5V, TJ= 25°C	7	8	9	Α
l	Iым Current Limit	Vcntl=5V, Tj= -25 ~ 125°C	6			Α
ILIM C		VCNTL=3.3V, TJ= 25°C	6.8	7.8	8.8	Α
		Vcntl=3.3V, Tj= -25 ~ 125°C	6			Α
Tsp	Thermal Shutdown Temperature	T _J Rising		150		°C
	Thermal Shutdown Hysteresis			50		°C
	Under-Voltage Threshold	V _{FB} Falling		0.4		V
ENABLE	and SOFT-START					
	EN Logic High Threshold Voltage	VEN Rising	0.3	0.4	0.5	V
	EN Hysteresis			30		mV
	EN Pin Pull-Up Current	EN=GND		10		μΑ
Tss	Soft-Start Interval			2		mS
POWER	OK and DELAY					,
Vрок	POK Threshold Voltage for Power OK	VFB Rising	90%	92%	94%	VREF
VPNOK	POK Threshold Voltage for Power Not OK	V _{FB} Falling	79%	81%	83%	VREF
	POK Low Voltage	POK sinks 5mA		0.25	0.4	V
TDELAY	POK Delay Time		1	3	10	mS

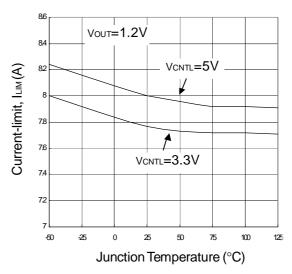


Typical Operating Characteristics

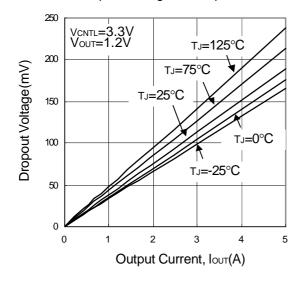
VCNTL Supply Current vs. Junction Temperature



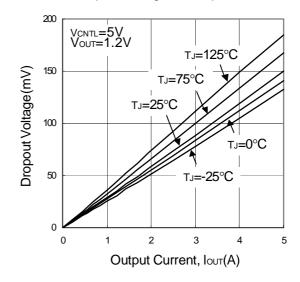
Current-limit vs. Junction Temperature



Dropout Voltage vs. Output Current



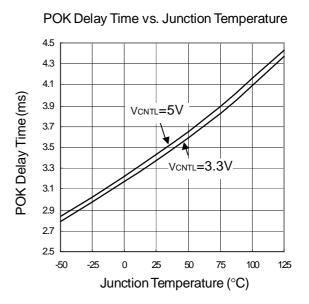
Dropout Voltage vs. Output Current

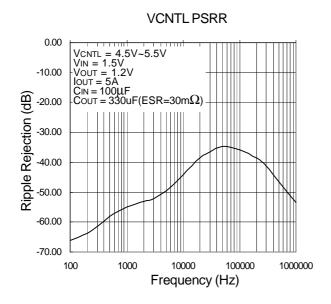


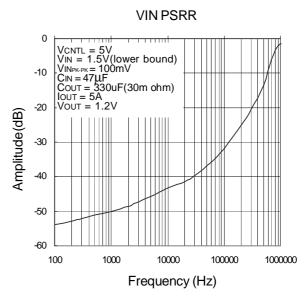


Typical Operating Characteristics

Reference Voltage vs. Junction Temperature Reference Voltage, VREF (mV) 0.806 0.804 0.802 0.800 0.798 0.796 0.794 0.792 25 50 100 75 125 Junction Temperature (°C)



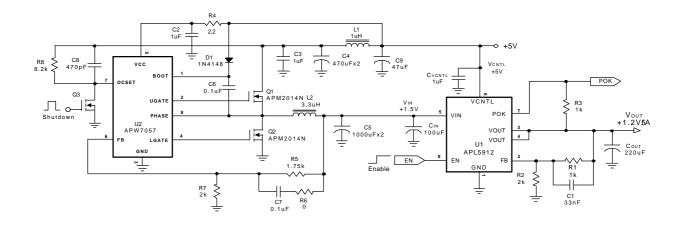






Operating Waveforms

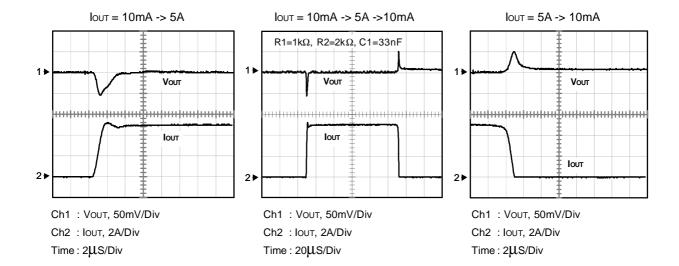
Test Circuit



1. Load transient Response

1.1 Using an Output Capacitor with ESR \geq 18m Ω

- Cout = $220\mu F/6.3V$ (ESR = $30m\Omega$), $C_{IN} = 100\mu F/6.3V$
- lout = 10mA to 5A to 10mA, Rise time = Fall time = 1 μ S

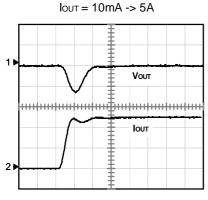




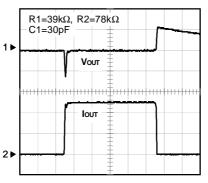
Operating Waveforms (Cont.)

1.2 Using an MLCC as the Output Capacitor

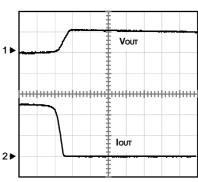
- Cout = $22\mu\text{F}/6.3\text{V}$ (ESR = $3\text{m}\Omega$), Cin = $22\mu\text{F}/6.3\text{V}$
- Iout = 10mA to 5A to 10mA, Rise time = Fall time = $1\mu S$



IOUT = 10mA -> 5A -> 10mA



Ιουτ = 5A -> 10mA



Ch1: Vout, 100mV/Div

Ch2: Iout, 2A/Div Time: 2µS/Div

Ch1: Vout, 100mV/Div

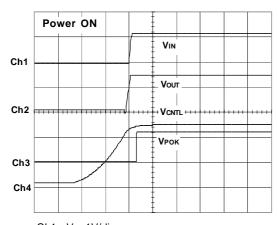
Ch2: Iout, 2A/Div Time: 20µS/Div

Ch1: Vout, 100mV/Div

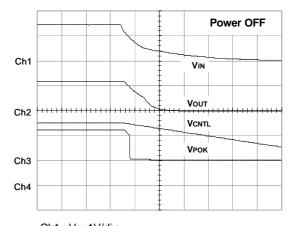
Ch2: Iout, 2A/Div Time: 2µS/Div

2. Power ON / Power OFF:

- $V_{IN} = 1.5V, V_{CNTL} = 5V, V_{OUT} = 1.2V$
- Cout = $220\mu F/6.3V$ (ESR = $30m\Omega$), $C_{IN} = 100\mu F/6.3V$, $R_{L} = 1\Omega$



Ch1: VIN,1V/div Ch2: Vout,1V/div Ch3: VPOK.1V/div Ch4: VCNTL, 2V/div Time: 10ms/div



Ch1: VIN,1V/div Ch2: Vout,1V/div Ch3: VPOK,1V/div Ch4: Vcntl,2V/div

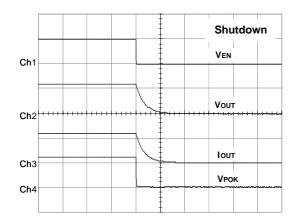
Time: 10ms/div



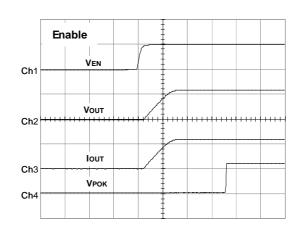
Operating Waveforms (Cont.)

3. Shutdown and Enable:

- $V_{IN} = 1.5V, V_{CNTL} = 5V, V_{OUT} = 1.2V$
- Cout = 220 μ F/6.3V (ESR = 30m Ω), CN = 100 μ F/6.3V, RL = 1 Ω



Ch1: VEN,5V/div Ch2: VOUT,1V/div Ch3: lout,1A/div Ch4: VPOK,1V/div

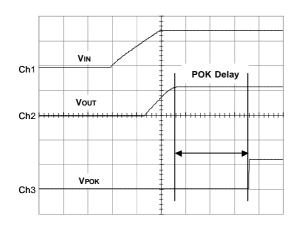


Ch1: VEN,5V/div Ch2: VOUT,1V/div Ch3: buT,1A/div Ch4: VPOK,1V/div Time: 1ms/div

4. POK Delay:

Time: 1ms/div

- $V_{IN} = 1.5V, V_{CNTL} = 5V, V_{OUT} = 1.2V$
- Cout = $220\mu F/6.3V$ (ESR = $30m\Omega$), C_{IN} = $100\mu F/6.3V$, R_{L} = 1Ω



Ch1: VIN,1V/div Ch2: VOUT,1V/div Ch3: VPOK,1V/div Time: 1ms/div



Functional Pin Description

GND (Pin 1)

Ground pin of the circuitry. All voltage levels are measured with respect to this pin.

FB (Pin 2)

Connecting this pin to an external resistor divider receives the feedback voltage of the regulator. The output voltage set by the resistor divider is determined by:

 $V_{\text{OUT}} = 0.8 \cdot \left(1 + \frac{R1}{R2}\right) \tag{V}$

where R1 is connected from VOUT to FB with Kelvin sensing and R2 is connected from FB to GND. A bypass capacitor may be connected with R1in parallel to improve load transient response. The recommended R2 and R1 are in the range of $100 \sim 10 k\Omega$.

VOUT (Pin 3,4)

Output of the regulator. Please connect Pin 3 and 4 together using wide tracks. It is necessary to connect a output capacitor with this pin for closed-loop compensation and improving transient responses.

VIN (Pin 5) and Exposed Pad

Main supply input pins for power conversions. The Exposed Pad provide a very low impedance input path

for the main supply voltage. Please tie the Exposed Pad and VIN Pin (Pin 8) together to reduce the dropout voltage. The voltage at this pins is monitored for Power-On Reset purpose.

VCNTL (Pin 6)

Power input pin of the control circuitry. Connecting this pin to a +5V (recommended) supply voltage provides the bias for the control circuitry. The voltage at this pin is monitored for Power-On Reset purpose.

POK (Pin 7)

Power-OK signal output pin. This pin is an open-drain output used to indicate status of output voltage by sensing FB voltage. This pin is pulled low when the rising FB voltage is not above the VPOK threshold or the falling FB voltage is below the VPNOK threshold, indicating the output is not OK.

EN (Pin 8)

Enable control pin. Pulling and holding this pin below 0.3V shuts down the output. When re-enabled, the IC undergoes a new soft-start cycle. Left this pin open, an internal current source $10\mu\text{A}$ pulls this pin up to VCNTL voltage, enabling the regulator.

Functional Description

Power-On-Reset

A Power-On-Reset (POR) circuit monitors both input voltages at VCNTL and VIN pins to prevent wrong logic controls. The POR function initiates a soft-start process after the two supply voltages exceed their rising POR threshold voltages during powering on. The POR function also pulls low the POK pin regardless the output voltage when the VCNTL voltage falls below it's falling POR threshold.

Internal Soft-Start

An internal soft-start function controls rise rate of the output voltage to limit the current surge at start-up. The typical soft-start interval is about 2mS.

Output Voltage Regulation

An error amplifier working with a temperature-compensated 0.8V reference and an output NMOS regulates output to the preset voltage. The error amplifier designed with



Functional Description (Cont.)

Output Voltage Regulation (Cont.)

high bandwidth and DC gain provides very fast transient response and less load regulation. It compares the reference with the feedback voltage and amplifies the difference to drive the output NMOS which provides load current from VIN to VOUT.

Current-Limit

The APL5912 monitors the current via the output NMOS and limits the maximum current to prevent load and APL5912 from damages during overload or short-circuit conditions.

Under-Voltage Protection (UVP)

The APL5912 monitors the voltage on FB pin after softstart process is finished. Therefore the UVP is disable during soft-start. When the voltage on FB pin falls below the under-voltage threshold, the UVP circuit shuts off the output immediately. After a while, the APL5912 starts a new soft-start to regulate output.

Thermal Shutdown

A thermal shutdown circuit limits the junction temperature of APL5912. When the junction temperature exceeds +150°C, a thermal sensor turns off the output NMOS, allowing the device to cool down. The regulator regulates the output again through initiation of a new soft-start cycle after the junction temperature cools by 50°C, resulting in a pulsed output during continuous

Application Information

Power Sequencing

The power sequencing of VIN and VCNTL is not necessary to be concerned. But do not apply a voltage to VOUT for a long time when the main voltage applied at VIN is not present. The reason is the internal parasitic diode from VOUT to VIN conducts and dissipates power without protections due to the forward-voltage.

thermal overload conditions. The thermal shutdown designed with a 50°C hysteresis lowers the average junction temperature during continuous thermal overload conditions, extending life time of the device.

For normal operation, device power dissipation should be externally limited so that junction temperatures will not exceed +125°C.

Enable Control

The APL5912 has a dedicated enable pin (EN). A logic low signal (Ven< 0.3V) applied to this pin shuts down the output. Following a shutdown, a logic high signal re-enables the output through initiation of a new softstart cycle. Left open, this pin is pulled up by an internal current source (10 μ A typical) to enable operation. It's not necessary to use an external transistor to save cost.

Power-OK and Delay

The APL5912 indicates the status of the output voltage by monitoring the feedback voltage (VFB) on FB pin. As the VFB rises and reaches the rising Power-OK threshold (VPOK), an internal delay function starts to perform a delay time. At the end of the delay time, the IC turns off the internal NMOS of the POK to indicate the output is OK. As the VFB falls and reaches the falling Power-OK threshold (VPNOK), the IC immediately turns on the NMOS of the POK to indicate the output is not OK without a delay time.

Output Capacitor

The APL5912 requires a proper output capacitor to maintain stability and improve transient response over temperature and current. The output capacitor selection is to select proper ESR (equivalent series resistance) and capacitance of the output capacitor for good stability and load transient response.



Application Information (Cont.)

Output Capacitor (Cont.)

The APL5912 is designed with a programmable feedback compensation adjusted by an external feedback network for the use of wide ranges of ESR and capacitance in all applications. Ultra-low-ESR capacitors (such as ceramic chip capacitors), low-ESR bulk capacitors (such as solid tantalum, POSCap, and Aluminum electrolytic capacitors) can all be used as an output capacitor. The value of the output capacitors can be increased without limit.

During load transients, the output capacitors, depending on the stepping amplitude and slew rate of load current, are used to reduce the slew rate of the current seen by the APL5912 and help the device to minimize the variations of output voltage for good transient response. For the applications with large stepping load current, the low-ESR bulk capacitors are normally recommended.

Decoupling ceramic capacitors must be placed at the load and ground pins as close as possible and the impedance of the layout must be minimized.

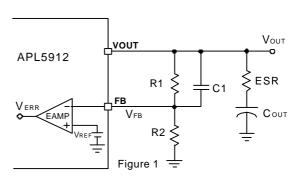
Input Capacitor

The APL5912 requires proper input capacitors to supply current surge during stepping load transients to prevent the input rail from dropping. Because the parasitic inductor from the voltage sources or other bulk capacitors to the VIN pin limit the slew rate of the surge currents. More parasitic inductance needs more input capacitance.

Ultra-low-ESR capacitors, such as ceramic chip capacitors, are very good for the input capacitors. An aluminum electrolytic capacitor (>100 $\mu\text{F}, \text{ESR} < 300\text{m}\Omega)$ is recommended as the input capacitor. It is not necessary to use low-ESR capacitors. More capacitance reduce the variations of the input voltage of VIN pin.

Feedback Network

Figure 1 shows the feedback network between VOUT, GND and FB pins. It works with the internal error amplifier to provide proper frequency response for the linear regulator. The ESR is the equivalent series resistance of the output capacitor. The Cout is ideal capacitance in the output capacitor. The Vout is the setting of the output voltage.



The feedback network selection, depending on the values of the ESR and C_{OUT} , has been classified into three conditions :

• Condition 1 : Large ESR (≥18mΩ)

- Select the R1 in the range of $400\Omega \sim 2.4k\Omega$
- Calculate the R2 as the following: $R2_{(k\Omega)} = R1_{(k\Omega)} \cdot \frac{0.8_{(V)}}{V_{OUT(V)} 0.8_{(V)}} \ \dots \dots \dots (1)$
- Calculate the C1 as the following:

$$10 \cdot \frac{V_{OUT(V)}}{R1_{(K\Omega)}} \le C1_{(nF)} \le 40 \cdot \frac{V_{OUT(V)}}{R1_{(K\Omega)}} \dots (2)$$

• Condition 2 : Middle ESR

- Calculate the R1 as the following:

$$R1_{(k\Omega)} = \frac{1500}{ESR_{(m\Omega)}} - 37.5 \cdot V_{OUT(V)} + 30 \dots (3)$$

Select a proper R1_(selected) to be a little larger than the calculated R1.

- Calculate the C1 as the following:

$$C1_{(pF)} = \left[ESR_{(m\Omega)} + 50\right] \cdot \frac{C_{OUT(uF)}}{R1_{(k\Omega)}} \quad \tag{4}$$
 Where R1=R1_(selected)

Select a proper C1_(selected) to be a little smaller than



Application Information (Cont.)

Feedback Network (Cont.)

the calculated C1.

 The C1 calculated from equation (4) must meet the following equation:

$$C1_{(pF)} \geq 5.1 \cdot \left[1 + \frac{50}{ESR_{(m\Omega)}}\right] \cdot \left[1 + \frac{37.5 \cdot V_{OUT(V)}}{R1_{(k\Omega)}}\right] ...(5)$$

Where R1=R1(calculated) from equation (3)

If the C1_(calculated) can not meet the equation (5), please use the Condition 3.

- Use equation (2) to calculate the R2.
- Condition 3: Low ESR (eg. Ceramic Capacitors)
- Calculate the R1 as the following:

$$R1_{(k\Omega)} = \sqrt{(5.9 \cdot ESR_{m\Omega}) + 294} \cdot C_{OUT(uF)} - 37.5 \cdot V_{OUT(V)}...(6)$$

Select a proper R1_(selected) to be a little larger than the calculated R1. *The minimum selected R1* is equal to $1k\Omega$ when the calculated R1 is smaller than 1k or negative.

- Calculate the C1 as the following:

$$C1_{(pF)} = \sqrt{(0.17 \cdot ESR_{(m\Omega)} + 8.5) \cdot C_{OUT(uF)}} \cdot \left[1 + \frac{37.5 \cdot V_{OUT(V)}}{R1_{(k\Omega)}}\right]...(7)$$

Where R1=R1(selected)

Select a proper C1_(selected) to be a little smaller than the calculated C1.

 The C1 calculated from equation (7) must meet the following equation:

$$C1_{(pF)} \ge \left[0.033 + \frac{1.25 \cdot V_{OUT(V)}}{R1_{(k\Omega)}}\right] \cdot ESR_{(m\Omega)} \cdot C_{OUT(uF)} ...(8)$$
Where R1=R1_(calculated) from equation (6)

If the C1_(calculated) can not meet the equation (8), please use the Condition 2.

- Use equation (2) to calculate the R2.

The reason to have three conditions described above is to optimize the load transient responses for all kinds of the output capacitor. For stability only, the Condition 2, regardless of equation (5), is enough for all kinds of output capacitor.

PCB Layout Considerations (See Figure 2)

- Please solder the Exposed Pad and VIN together on the PCB. The main current flow is through the exposed pad. The role of VIN is a voltage sense. Refer Figure 3 to make a proximate topology.
- 2. Please place the input capacitors for VIN and VCNTL pins near pins as close as possible.
- 3. Ceramic decoupling capacitors for load must be placed near the load as close as possible.
- 4. To place APL5912 and output capacitors near the load is good for performance.
- 5. The negative pins of the input and output capacitors and the GND pin of the APL5912 are connected to the ground plane of the load.
- 6. Please connect PIN 3 and 4 together by a wide track or plane on the Top layer.
- 7. Large current paths must have wide tracks.
- 8. See the Typical Application
 - Connect the one pin of the R2 to the GND of APL5912.

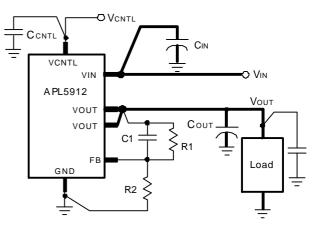


Figure 2

- Connect the one pin of R1 to the Pin 3 of APL5912
- Connect the one pin of C1 to the Pin 3 of APL5912



Application Information (Cont.)

Thermal Considerations

See Figure 3. The SOP-8-P is a cost-effective package featuring a small size like a standard SOP-8 and a bottom exposed pad to minimize the thermal resistance of the package, being applicable to high current applications. The exposed pad must be soldered to the top V_{IN} plane. The copper of the V_{IN} plane on the Top layer conducts heat into the PCB and air. Please enlarge the area to reduce the case-to-ambient resistance ($_{\text{CA}}$).

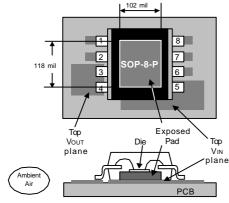
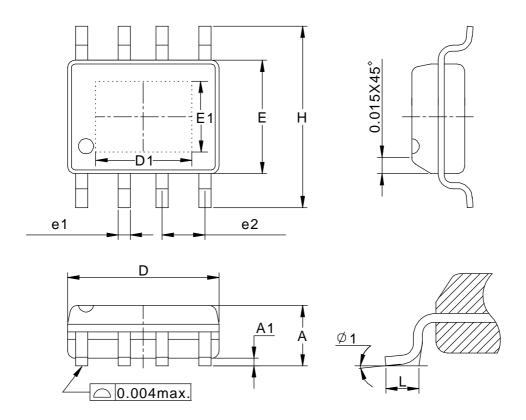


Figure 3



Packaging Information

SOP-8-P pin (Reference JEDEC Registration MS-012)



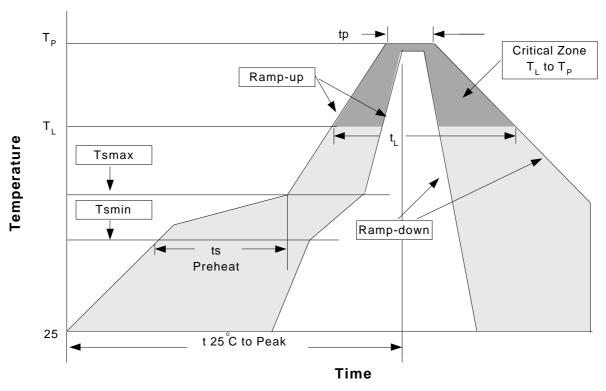
Dim	Millim	neters	Incl	nes
Biiii	Min.	Max.	Min.	Max.
А	1.35	1.75	0.053	0.069
A1	0	0.15	0	0.006
D	4.80	5.00	0.189	0.197
D1	3.00REF		0.118REF	
Е	3.80	4.00	0.150	0.157
E1	2.60	REF	0.102REF	
Н	5.80	6.20	0.228	0.244
L	0.40	1.27	0.016	0.050
e1	0.33	0.51	0.013	0.020
e2	1.27BSC		0.50BSC	
φ 1	8	0	8	0



Physical Specifications

Terminal Material	Solder-Plated Copper (Solder Material: 90/10 or 63/37 SnPb), 100%Sn
Lead Solderability	Meets EIA Specification RSI86-91, ANSI/J-STD-002 Category 3.

Reflow Condition (IR/Convection or VPR Reflow)



Classificatin Reflow Profiles

Profile Feature	Sn-Pb Eutectic Assembly	Pb-Free Assembly
Average ramp-up rate $(T_L \text{ to } T_P)$	3°C/second max.	3°C/second max.
Preheat - Temperature Min (Tsmin) - Temperature Max (Tsmax) - Time (min to max) (ts)	100°C 150°C 60-120 seconds	150°C 200°C 60-180 seconds
Time maintained above: - Temperature (T _L) - Time (t _L)	183°C 60-150 seconds	217°C 60-150 seconds
Peak/Classificatioon Temperature (Tp)	See table 1	See table 2
Time within 5°C of actual Peak Temperature (tp)	10-30 seconds	20-40 seconds
Ramp-down Rate	6°C/second max.	6°C/second max.
Time 25°C to Peak Temperature	6 minutes max.	8 minutes max.

Notes: All temperatures refer to topside of the package .Measured on the body surface.



Classificatin Reflow Profiles(Cont.)

Table 1. SnPb Entectic Process – Package Peak Reflow Temperatures

Package Thickness	Volume mm ³ <350	Volume mm ³
<2.5 mm	240 +0/-5°C	225 +0/-5°C
≥2.5 mm	225 +0/-5°C	225 +0/-5°C

Table 2. Pb-free Process – Package Classification Reflow Temperatures

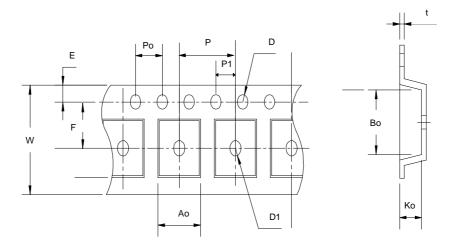
Package Thickness	Volume mm³ <350	Volume mm ³ 350-2000	Volume mm ³ >2000
<1.6 mm	260 +0°C*	260 +0°C*	260 +0°C*
1.6 mm – 2.5 mm	260 +0°C*	250 +0°C*	245 +0°C*
≥2.5 mm	250 +0°C*	245 +0°C*	245 +0°C*

^{*}Tolerance: The device manufacturer/supplier **shall** assure process compatibility up to and including the stated classification temperature (this means Peak reflow temperature +0°C. For example 260°C+0°C) at the rated MSL level.

Reliability Test Program

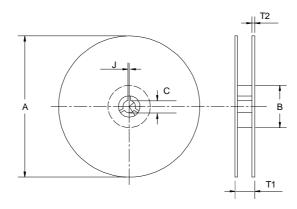
Test item	Method	Description
SOLDERABILITY	MIL-STD-883D-2003	245°C, 5 SEC
HOLT	MIL-STD-883D-1005.7	1000 Hrs Bias @125°C
PCT	JESD-22-B,A102	168 Hrs, 100%RH, 121°C
TST	MIL-STD-883D-1011.9	-65°C~150°C, 200 Cycles
ESD	MIL-STD-883D-3015.7	VHBM > 2KV, VMM > 200V
Latch-Up	JESD 78	$10ms, 1_{tr} > 100mA$

Carrier Tape





Carrier Tape(Cont.)



Application	Α	В	С	J	T1	T2	W	Р	E
SOP- 8/-P	330 ± 1	62 +1.5	12.75+ 0.15	2 ± 0.5	12.4 ± 0.2	2 ± 0.2	12± 0. 3	8± 0.1	1.75±0.1
	F	D	D1	Po	P1	Ao	Во	Ko	t
	5.5± 1	1.55 +0.1	1.55+ 0.25	4.0 ± 0.1	2.0 ± 0.1	6.4 ± 0.1	5.2± 0. 1	2.1± 0.1	0.3±0.013

(mm)

Cover Tape Dimensions

Application	Carrier Width	Cover Tape Width	Devices Per Reel
SOP- 8/-P	12	9.3	2500

Customer Service

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